www.ti.com

# MAX3243-EP 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD (HBM) PROTECTION

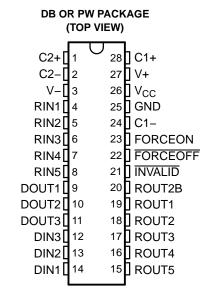
SGLS328A-MARCH 2006-REVISED MAY 2006

#### **FEATURES**

- Controlled Baseline
  - One Assembly/Test Site, One Fabrication Site
- Extended Temperature Performance of -55°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree (1)
- Single-Chip and Single-Supply Interface for IBM™ PC/AT™ Serial Port
- RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)
- D Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V<sub>CC</sub> Supply
- Three Drivers and Five Receivers
- Low Standby Current . . . 1 mA Typical
- External Capacitors . . . 4 × 0.1 mF
- Accepts 5-V Logic Input With 3.3-V Supply
- Always-Active Noninverting Receiver Output (ROUT2B)
- Serial-Mouse Driveability
- Auto-Powerdown Feature to Disable Driver Outputs When No Valid RS-232 Signal Is Sensed
- (1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

#### Applications

Battery-Powered Systems, PDAs,
 Notebooks, Laptops, Palmtop PCs, and
 Hand-Held Equipment



#### **DESCRIPTION**

The MAX3243 consists of three line drivers, five line receivers, and a dual charge-pump circuit with  $\pm 15$ -kV ESD (HBM) protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. This combination of drivers and receivers matches that needed for the typical serial port used in an IBM PC/AT or compatible. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. In addition, the device includes an always-active noninverting output (ROUT2B), which allows applications using the ring indicator to transmit data while the device is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

IBM, PC/AT are trademarks of IBM.

### **MAX3243-EP**

# 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH $\pm$ 15-kV ESD (HBM) PROTECTION



SGLS328A-MARCH 2006-REVISED MAY 2006

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and  $\overline{FORCEOFF}$  is high. During this mode of operation, if the device does not sense a valid RS-232 signal, the driver outputs are disabled. If  $\overline{FORCEOFF}$  is set low, both drivers and receivers (except ROUT2B) are shut off and the supply current is reduced to 1  $\mu$ A. Disconnecting the serial port or turning off the peripheral drivers causes the auto-powerdown condition to occur.

Auto-powerdown can be disabled when FORCEON and  $\overline{\text{FORCEOFF}}$  are high and should be done when driving a serial mouse. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to any receiver input. The  $\overline{\text{INVALID}}$  output is used to notify the user if an RS-232 signal is present at any receiver input.  $\overline{\text{INVALID}}$  is high (valid data) if any receiver input voltage is greater than 2.7 V or less than -2.7 V or has been between -0.3 V and 0.3 V for less than 30  $\mu$ s.  $\overline{\text{INVALID}}$  is low (invalid data) if all receiver input voltages are between -0.3 V and 0.3 V for more than 30  $\mu$ s. See Figure 5 for receiver input levels.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
55°C to 125°C	SSOP – DB	Reel of 2000	MAX3243MDBREP	MB3243M
–55°C to 125°C	TSSOP - PW	Reel of 2000	MAX3243MPWREP	MB3243M

<sup>(1)</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLES**

#### Each Driver(1)

	INP	UTS		OUTDUT	
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL	OUTPUT DOUT	DRIVER STATUS
X	X	L	X	Z	Powered off
L	Н	Н	X	Н	Normal operation with auto-powerdown
Н	Н	Н	X	L	disabled
L	L	Н	YES	Н	Normal operation with auto-powerdown
Н	L	Н	YES	L	enabled
L	L	Н	NO	Z	Dower off by outo powerdown feeture
Н	L	Н	NO	Z	Power off by auto-powerdown feature

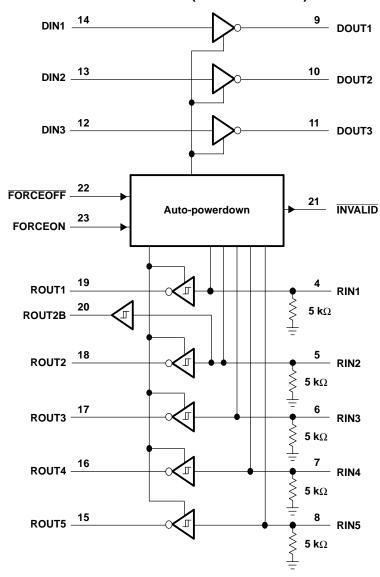
#### (1) H = high level, L = low level, X = irrelevant, Z = high impedance

#### Each Receiver<sup>(1)</sup>

	INP	UTS		OUT	PUTS	
RIN2	RIN1, RIN3–RIN5	FORCEOFF	VALID RIN RS-232 LEVEL	ROUT2B	ROUT	RECEIVER STATUS
L	Х	L	Х	L	Z	Powered off while ROUT2B is active
Н	X	L	X	Н	Z	Powered on while ROOT2B is active
L	L	Н	YES	L	Н	
L	Н	Н	YES	L	L	
Н	L	Н	YES	Н	Н	Normal operation with auto-powerdown disabled/enabled
Н	Н	Н	YES	Н	L	alloabloa/chablea
Open	Open	Н	YES	L	Н	

<sup>(1)</sup> H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

#### **LOGIC DIAGRAM (POSITIVE LOGIC)**



# **MAX3243-EP**

# 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD (HBM) PROTECTION

SGLS328A-MARCH 2006-REVISED MAY 2006



#### Absolute Maximum Ratings (1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage range (2)		-0.3	6	V	
V+	Positive output supply voltage range <sup>(2)</sup>		-0.3	7	V	
V-	Negative output supply voltage range <sup>(2)</sup>		0.3	-7	V	
V+ - V-	Supply voltage difference <sup>(2)</sup>			13	V	
VI	Innut valtage renge	Driver (FORCEOFF, FORCEON)	-0.3	6	V	
	Input voltage range	Receiver	-25	25		
	Output voltage range	Driver	-13.2	13.2	V	
Vo		Receiver (INVALID)	-0.3	V <sub>CC</sub> + 0.3		
		DB package		62		
$\theta_{JA}$	Package thermal impedance (3)(4)	DW package		46	°C/W	
		PW package		62		
T <sub>J</sub>	Operating virtual junction temperature			150	°C	
T <sub>stg</sub>	Storage temperature range			150	°C	

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# Recommended Operating Conditions<sup>(1)</sup>

See Figure 6

				MIN	NOM	MAX	UNIT
	Supply voltage		V <sub>CC</sub> = 3.3 V	3	3.3	3.6	V
	Supply voltage		$V_{CC} = 5 V$	4.5	5	5.5	v
\/		========	$V_{CC} = 3.3 \text{ V}$	2			· \
VIH			V <sub>CC</sub> = 5 V	2.4			V
$V_{IL}$	Driver and control low-level input voltage	DIN, FORCEOFF, FORCE	CEON			0.8	٧
$V_{I}$	Driver and control input voltage	DIN, FORCEOFF, FORCE	CEON	0		5.5	٧
$V_{I}$	V <sub>I</sub> Receiver input voltage			-25		25	V
$T_A$	T <sub>A</sub> Operating free-air temperature			-55		125	°C

<sup>(1)</sup> Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ±0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ±0.5 V.

#### Electrical Characteristics (1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER		TEST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
I <sub>I</sub>	Input leakage current	FORCEOFF, FORCEON			±0.01	±1	μΑ
	Supply current	Auto-powerdown disabled	No load, FORCEOFF and FORCEON at V <sub>CC</sub>		0.3	2	mA
		Powered off	No load, FORCEOFF at GND		1	10	
I <sub>CC</sub>	Supply current $(T_A = 25^{\circ}C)$	Auto-powerdown enabled	No load, FORCEOFF at V <sub>CC</sub> , FORCEON at GND, All RIN are open or grounded, All DIN are grounded		1	20	μΑ

<sup>(1)</sup> Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ±0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ±0.5 V.

All voltages are with respect to network GND.

<sup>(3)</sup> Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is P<sub>D</sub> = (T<sub>J</sub>(max) - T<sub>A</sub>)/θ<sub>JA</sub>. Operating at the absolute maximum T<sub>J</sub> of 150°C can affect reliability.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### **DRIVER SECTION**

# Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TES	ST CONDITIONS		MIN	TYP <sup>(2)</sup>	MAX	UNIT
$V_{OH}$	High-level output voltage	All DOUT at $R_L = 3 \text{ k}\Omega$ to $\Omega$	All DOUT at $R_L = 3 \text{ k}\Omega$ to GND			5.4		V
$V_{OL}$	Low-level output voltage	All DOUT at $R_L = 3 \text{ k}\Omega$ to $\Omega$	All DOUT at $R_L = 3 \text{ k}\Omega$ to GND			-5.4		V
Vo	Output voltage (mouse driveability)	DIN1 = DIN2 = GND, DIN3 = $V_{CC}$ , 3-k $\Omega$ to GND at DOUT3, DOUT1 = DOUT2 = 2.5 mA			±5			V
I <sub>IH</sub>	High-level input current	$V_I = V_{CC}$				±0.01	±1	μΑ
$I_{\rm IL}$	Low-level input current	V <sub>I</sub> at GND				±0.01	±1	μΑ
V <sub>hys</sub>	Input hysteresis						±1	V
	Short-circuit output current <sup>(3)</sup>	V <sub>CC</sub> = 3.6 V,	V <sub>O</sub> = 0 V			±35	±60	mA
Ios	Short-circuit output current	$V_{CC} = 5.5 V,$	$V_O = 0 V$			±35	±00	ША
r <sub>o</sub>	Output resistance	$V_{CC}$ , V+, and V- = 0 V,	$V_O = \pm 2 V$		300	10M		Ω
	Output lookage ourrent	FORCEOFF = GND,	V <sub>O</sub> = ±12 V,	$V_{CC} = 3 \text{ to } 3.6 \text{ V}$			±25	^
I <sub>off</sub>	Output leakage current	FURGEOFF = GND,	$V_0 = \pm 10 \text{ V},$	$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$				μΑ

<sup>(1)</sup> Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$ 0.5 V. (2) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C.

## Switching Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

PARAMETER TES			EST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
	Maximum data rate	C <sub>L</sub> = 1000 pF, One DOUT switching,	$R_L = 3 \text{ k}\Omega$ , See Figure 1	150	250		kbit/s
t <sub>sk(p)</sub>	Pulse skew <sup>(3)</sup>	C <sub>L</sub> = 150 pF to 2500 pF,	$R_L = 3 \text{ k}\Omega$ to 7 k $\Omega$ , See Figure 2		100		ns
CD(+r)	Slew rate, transition region	V <sub>CC</sub> = 3.3 V,	C <sub>L</sub> = 150 pF to 1000 pF	6		30	1//
SR(tr)	(see Figure 1)	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega$	C <sub>L</sub> = 150 pF to 2500 pF	4		30	V/μs

<sup>(1)</sup> Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V + 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$ 0.5 V. (2) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C. (3) Pulse skew is defined as  $|t_{PLH} - t_{PHL}|$  of each channel of the same device.

#### RECEIVER SECTION

#### Electrical Characteristics (1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
V <sub>OH</sub>	High-level output voltage	$I_{OH} = -1 \text{ mA}$	V <sub>CC</sub> - 0.6	V <sub>CC</sub> - 0.1		V
V <sub>OL</sub>	Low-level output voltage	I <sub>OH</sub> = 1.6 mA			0.4	V
	Design and a standard design and all and the second	V <sub>CC</sub> = 3.3 V		1.6	2.4	V
V <sub>IT+</sub>	Positive-going input threshold voltage	V <sub>CC</sub> = 5 V		1.9	2.4	
\/	Negative going input throubold valtage	V <sub>CC</sub> = 3.3 V	0.6	1.1		V
$V_{IT-}$	Negative-going input threshold voltage	V <sub>CC</sub> = 5 V	0.8	1.4		
V <sub>hys</sub>	Input hysteresis (V <sub>IT+</sub> – V <sub>IT-</sub> )			0.5		V

Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$ 0.5 V. All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C.

Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

# **MAX3243-EP**

# 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD (HBM) PROTECTION

SGLS328A-MARCH 2006-REVISED MAY 2006



#### **Electrical Characteristics (continued)**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
I <sub>off</sub>	Output leakage current (except ROUT2B)	FORCEOFF = 0 V		±0.05	±10	μΑ
r <sub>l</sub>	Input resistance	$V_I = \pm 3 \text{ V or } \pm 25 \text{ V}$	3	5	8	kΩ

# Switching Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TYP <sup>(2)</sup>	UNIT
t <sub>PLH</sub>	Propagation delay time, low- to high-level output	C <sub>L</sub> = 150 pF, See Figure 3	150	ns
t <sub>PHL</sub>	Propagation delay time, high- to low-level output		150	ns
t <sub>en</sub>	Output enable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega, \text{ See Figure 4}$	200	ns
t <sub>dis</sub>	Output disable time		200	ns
t <sub>sk(p)</sub>	Pulse skew <sup>(3)</sup>	See Figure 3	50	ns

- (1) Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$ 0.5 V. (2) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C. (3) Pulse skew is defined as  $|t_{PLH} t_{PHL}|$  of each channel of the same device.

#### **AUTO-POWERDOWN SECTION**

#### **Electrical Characteristics**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
V <sub>IT+(valid)</sub>	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, FORCEOFF = V <sub>CC</sub>		2.7	V
V <sub>IT-(valid)</sub>	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, FORCEOFF = V <sub>CC</sub>	-2.7		V
V <sub>T(invalid)</sub>	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND, FORCEOFF = V <sub>CC</sub>	-0.3	0.3	V
V <sub>OH</sub>	INVALID high-level output voltage	I <sub>OH</sub> = -1 mA, FORCEON = GND, FORCEOFF = V <sub>CC</sub>	V <sub>CC</sub> - 0.		V
V <sub>OL</sub>	INVALID low-level output voltage	$I_{OL}$ = 1.6 mA, FORCEON = GND, FORCEOFF = $V_{CC}$		0.4	V

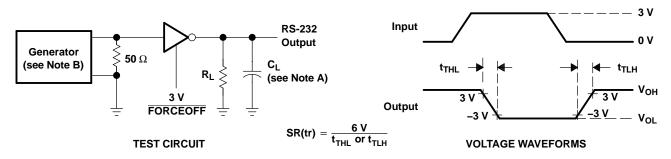
#### **Switching Characteristics**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	TYP <sup>(1)</sup>	UNIT
t <sub>valid</sub>	Propagation delay time, low- to high-level output	V <sub>CC</sub> = 5 V	1	μs
t <sub>invalid</sub>	Propagation delay time, high- to low-level output	V <sub>CC</sub> = 5 V	30	μs
t <sub>en</sub>	Supply enable time	V <sub>CC</sub> = 5 V	100	μs

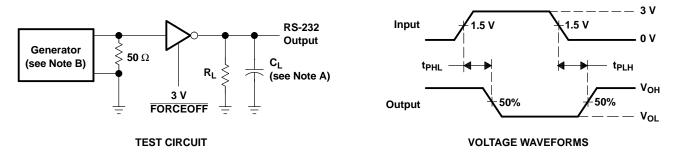
(1) All typical values are at  $V_{CC} = 3.3 \text{ V}$  or  $V_{CC} = 5 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$ .

#### PARAMETER MEASUREMENT INFORMATION



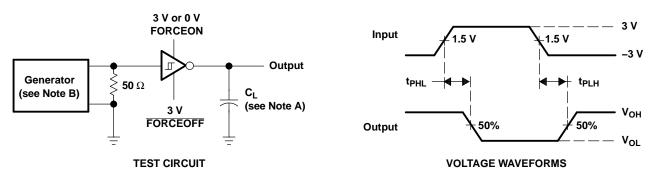
- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. The pulse generator has the following characteristics: PRR = 250 kbit/s

Figure 1. Driver Slew Rate



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_O = 50~\Omega$ , 50% duty cycle,  $t_f \le 10$  ns,  $t_f \le 10$  ns.

Figure 2. Driver Pulse Skew

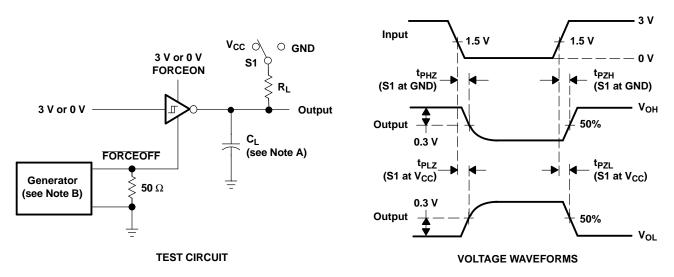


- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. The pulse generator has the following characteristics:  $Z_{O}$  = 50  $\Omega$ , 50% duty cycle,  $t_{r} \le 10$  ns,  $t_{f} \le 10$  ns.

Figure 3. Receiver Propagation Delay Times



#### PARAMETER MEASUREMENT INFORMATION

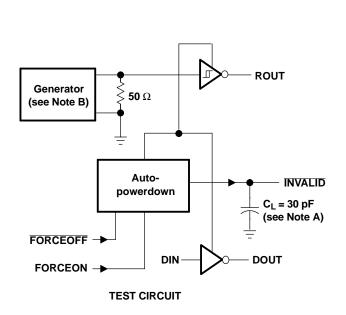


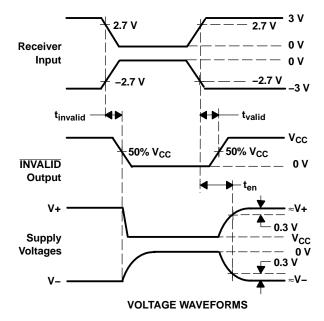
NOTES: A.  $C_L$  includes probe and jig capacitance.

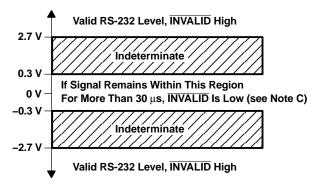
- B. The pulse generator has the following characteristics:  $Z_O = 50 \ \Omega$ , 50% duty cycle,  $t_f \le 10 \ ns$ .
- C.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- D. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.

Figure 4. Receiver Enable and Disable Times

#### PARAMETER MEASUREMENT INFORMATION







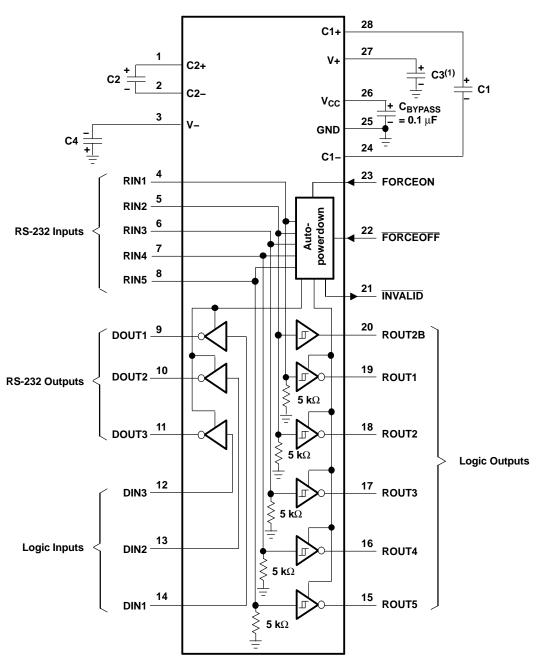
NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. The pulse generator has the following characteristics: PRR = 5 kbit/s,  $Z_O$  = 50  $\Omega$ , 50% duty cycle,  $t_r \le 10$  ns.  $t_f \le 10$  ns.
- C. Auto-powerdown disables drivers and reduces supply current to 1  $\mu$ A.

Figure 5. INVALID Propagation Delay Times and Supply Enabling Time



#### **APPLICATION INFORMATION**



(1) C3 can be connected to  $V_{CC}$  or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

#### V<sub>CC</sub> vs CAPACITOR VALUES

V <sub>CC</sub>	C1	C2, C3, and C4			
$\begin{array}{c} \textbf{3.3 V} \pm \textbf{0.3 V} \\ \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{3 V to 5.5 V} \end{array}$	0.1 μF 0.047 μF 0.1 μF	0.1 μF 0.33 μF 0.47 μF			

Figure 6. Typical Operating Circuit and Capacitor Values

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Jun-2022

#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MAX3243MDBREP	SSOP	DB	28	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
MAX3243MPWREP	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Jun-2022



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MAX3243MDBREP	SSOP	DB	28	2000	356.0	356.0	35.0
MAX3243MPWREP	TSSOP	PW	28	2000	356.0	356.0	35.0



SMALL OUTLINE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G28)

#### PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G28)

# PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



#### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022, Texas Instruments Incorporated